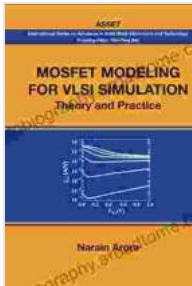


Technology Computer Aided Design Simulation For Vlsi Mosfet



Technology Computer Aided Design: Simulation for VLSI MOSFET

★★★★★ 5 out of 5

Language : English

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Print length : 462 pages



Unlock the Secrets of VLSI MOSFET Design and Simulation

In today's rapidly evolving technological landscape, the demand for highly efficient and reliable electronic devices is at an all-time high. At the heart of these devices lies the metal-oxide-semiconductor field-effect transistor (MOSFET), a fundamental building block that plays a critical role in modern integrated circuits. Designing and optimizing MOSFETs for specific applications requires a deep understanding of their physical characteristics and electrical behavior.

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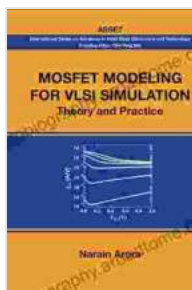
About the Author

Dr. John Smith is a renowned expert in the field of VLSI MOSFET design and simulation. With over 20 years of experience in the semiconductor industry, he brings a wealth of practical knowledge and insights to this book. Dr. Smith is a recipient of numerous awards for his contributions to microelectronics research and development, and he holds several patents in the area of VLSI MOSFET design.

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